## NSN 5962-00-433-6314



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-00-433-6314 **Body Length:** Between 1.200 inches and 1.290 inches **Body Width:** Between 0.515 inches and 0.580 inches **Body Height:** Between 0.050 inches and 0.230 inches **Maximum Power Dissipation Rating:** 650.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and negative outputs and positive outputs and bipolar and w/decoded output and w/enable and w/storage and programmable and programmed **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** P-type metal oxide-semiconductor logic **Input Circuit Pattern:** 11 input **Case Outline Source And Designator:** -0-015-aa joint electron device engineering council **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 0.3 volts power source **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 92755-12793 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

**Terminal Type And Quantity:** 

24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

**Demilitarization:** 

Yes - demil/mli

## NSN 5962-00-433-6314

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0